



# PMXB120EPE

30 V, P-channel Trench MOSFET

24 September 2013

Product data sheet

## 1. General description

P-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1010D-3 (SOT1215) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

## 2. Features and benefits

- Trench MOSFET technology
- Leadless ultra small and ultra thin SMD plastic package: 1.1 × 1.0 × 0.37 mm
- Exposed drain pad for excellent thermal conduction
- ElectroStatic Discharge (ESD) protection 1 kV HBM
- Drain-source on-state resistance  $R_{DSon} = 100 \text{ m}\Omega$

## 3. Applications

- High-side load switch and charging switch for portable devices
- Power management in battery driven portables
- LED driver
- DC-to-DC converter

## 4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DS}$	drain-source voltage	$T_j = 25 \text{ }^\circ\text{C}$	-	-	-30	V
$V_{GS}$	gate-source voltage		-20	-	20	V
$I_D$	drain current	$V_{GS} = -10 \text{ V}; T_{amb} = 25 \text{ }^\circ\text{C}$	[1]	-	-2.4	A
<b>Static characteristics</b>						
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = -10 \text{ V}; I_D = -2.4 \text{ A}; T_j = 25 \text{ }^\circ\text{C}$	-	100	120	m $\Omega$

[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.

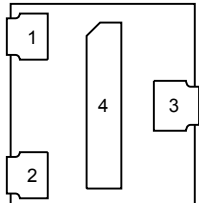
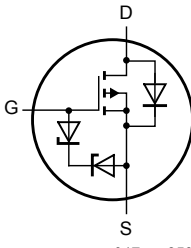


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### 5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate	 <p>Transparent top view DFN1010D-3 (SOT1215)</p>	 <p>017aaa259</p>
2	S	source		
3	D	drain		
4	D	drain		

### 6. Ordering information

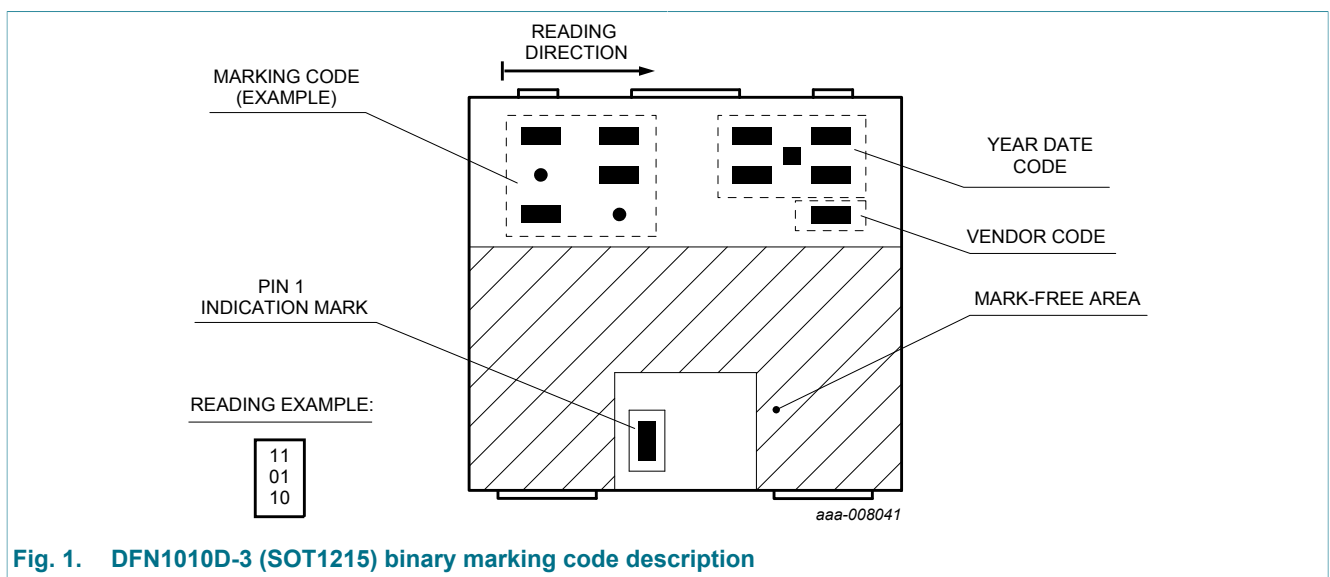
Table 3. Ordering information

Type number	Package		Version
	Name	Description	
PMXB120EPE	DFN1010D-3	plastic thermal enhanced ultra thin small outline package; no leads; 3 terminals; body 1.1 x 1.0 x 0.37 mm	SOT1215

### 7. Marking

Table 4. Marking codes

Type number	Marking code
PMXB120EPE	10 01 00



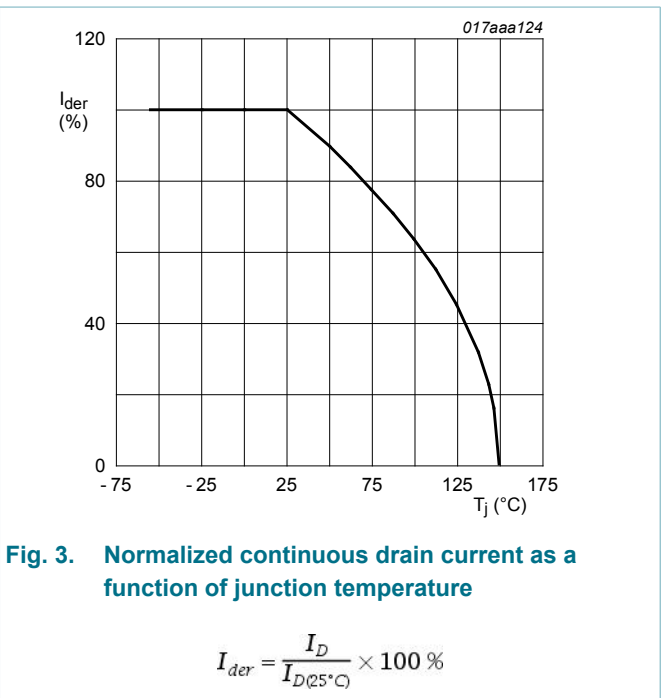
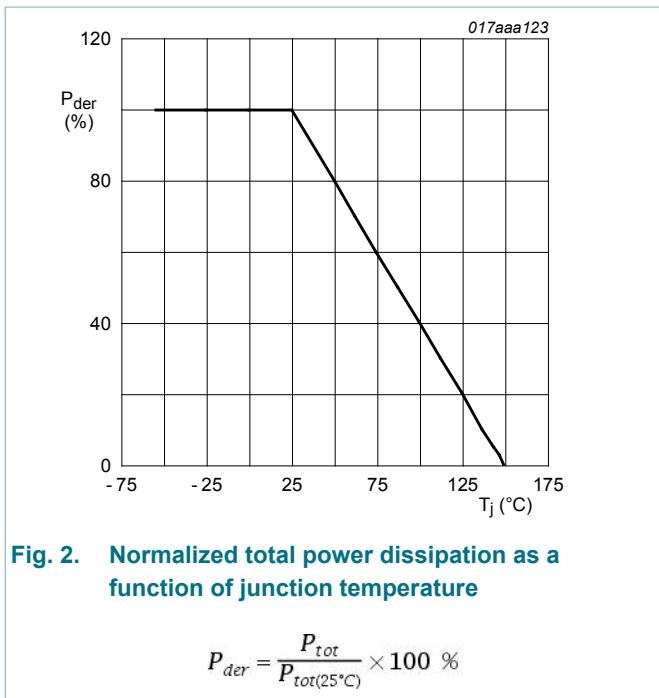
## 8. Limiting values

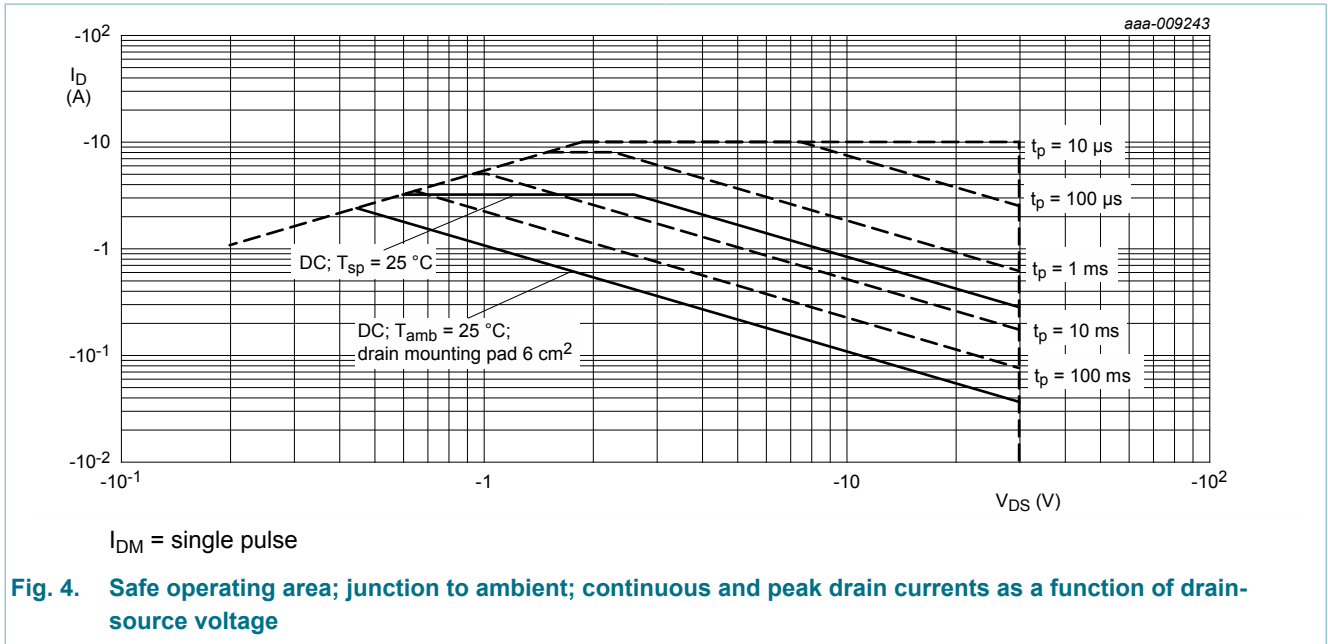
**Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V <sub>DS</sub>	drain-source voltage	T <sub>j</sub> = 25 °C		-	-30	V
V <sub>GS</sub>	gate-source voltage			-20	20	V
I <sub>D</sub>	drain current	V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 25 °C	[1]	-	-2.4	A
		V <sub>GS</sub> = -10 V; T <sub>amb</sub> = 100 °C	[1]	-	-1.5	A
I <sub>DM</sub>	peak drain current	T <sub>amb</sub> = 25 °C; single pulse; t <sub>p</sub> ≤ 10 μs		-	-10	A
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C	[2]	-	0.4	W
			[1]	-	1.07	W
		T <sub>sp</sub> = 25 °C		-	8.33	W
T <sub>j</sub>	junction temperature			-55	150	°C
T <sub>amb</sub>	ambient temperature			-55	150	°C
T <sub>stg</sub>	storage temperature			-65	150	°C
<b>Source-drain diode</b>						
I <sub>S</sub>	source current	T <sub>amb</sub> = 25 °C	[1]	-	-0.9	A

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 6 cm<sup>2</sup>.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.





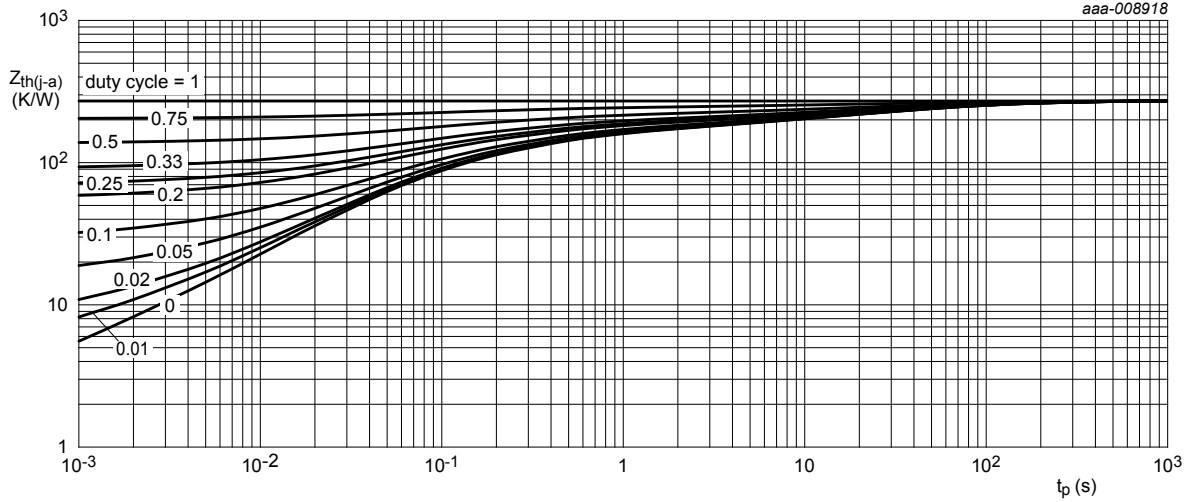
## 9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air	[1]	-	271	312	K/W
			[2]	-	102	117	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	10	15	K/W

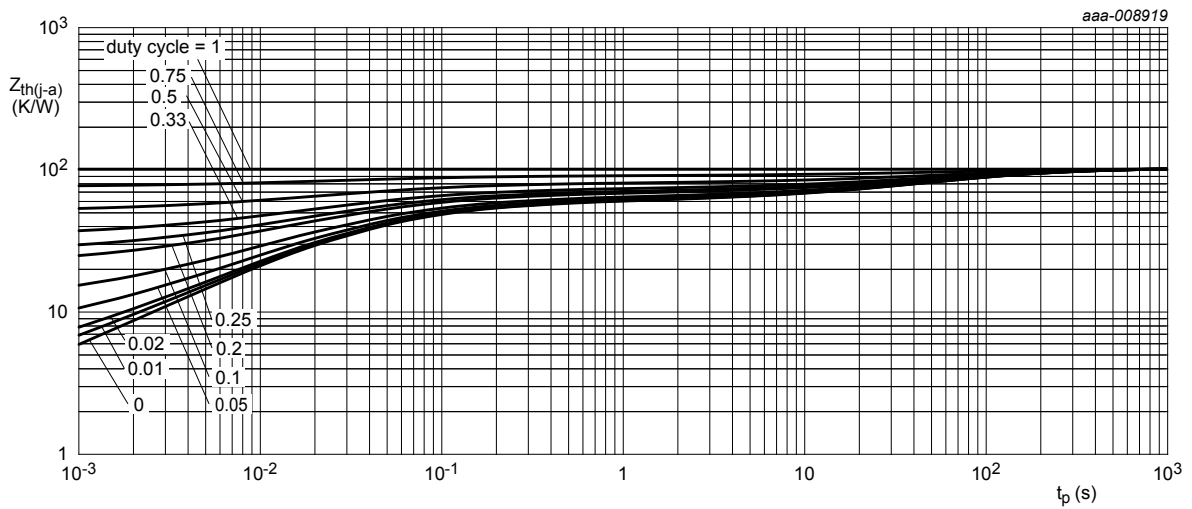
[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain  $6\text{ cm}^2$ .



FR4 PCB, standard footprint

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



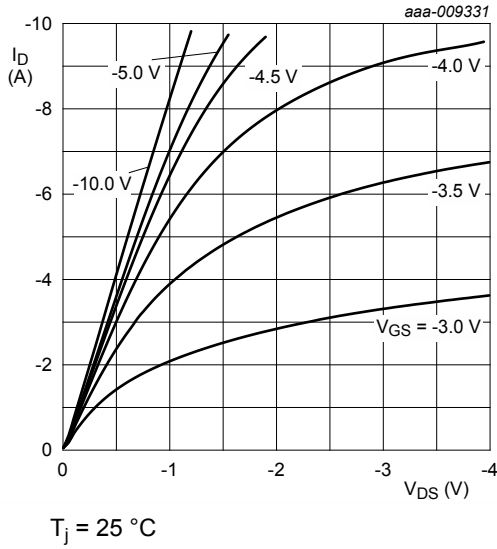
FR4 PCB, mounting pad for drain  $6\text{ cm}^2$

Fig. 6. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

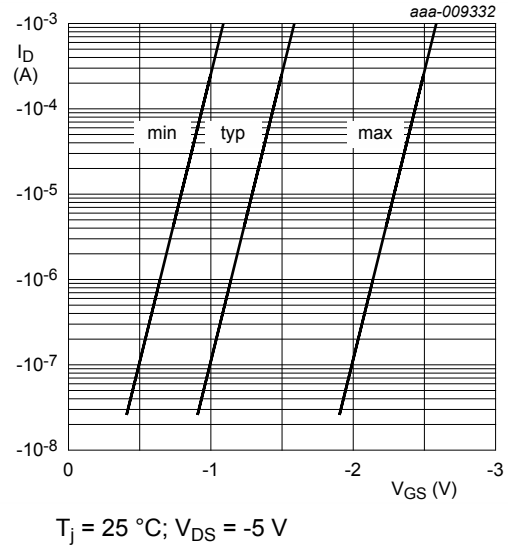
## 10. Characteristics

Table 7. Characteristics

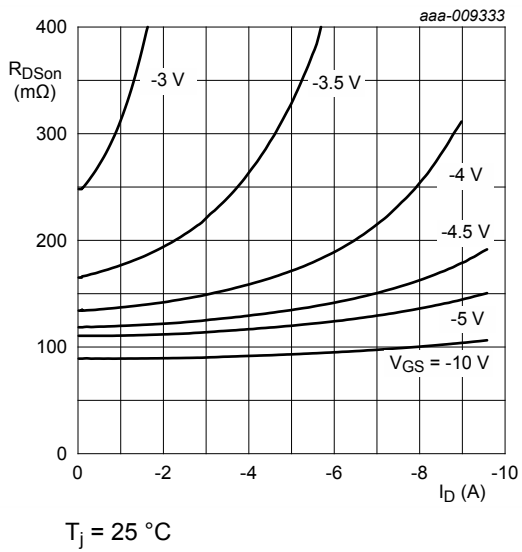
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>Static characteristics</b>						
$V_{(BR)DSS}$	drain-source breakdown voltage	$I_D = -250 \mu A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$	-30	-	-	V
$V_{GSth}$	gate-source threshold voltage	$I_D = -250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ }^\circ C$	-1	-1.5	-2.5	V
$I_{DSS}$	drain leakage current	$V_{DS} = -30 V; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$	-	-	-1	$\mu A$
$I_{GSS}$	gate leakage current	$V_{GS} = 16 V; V_{DS} = 0 V; T_j = 25 \text{ }^\circ C$	-	-	10	$\mu A$
		$V_{GS} = -16 V; V_{DS} = 0 V; T_j = 25 \text{ }^\circ C$	-	-	-10	$\mu A$
		$V_{GS} = 10 V; V_{DS} = 0 V; T_j = 25 \text{ }^\circ C$	-	-	1	$\mu A$
		$V_{GS} = -10 V; V_{DS} = 0 V; T_j = 25 \text{ }^\circ C$	-	-	-1	$\mu A$
$R_{DSon}$	drain-source on-state resistance	$V_{GS} = -10 V; I_D = -2.4 A; T_j = 25 \text{ }^\circ C$	-	100	120	m $\Omega$
		$V_{GS} = -10 V; I_D = -2.4 A; T_j = 150 \text{ }^\circ C$	-	156	187	m $\Omega$
		$V_{GS} = -4.5 V; I_D = -2 A; T_j = 25 \text{ }^\circ C$	-	125	170	m $\Omega$
$g_{fs}$	forward transconductance	$V_{DS} = -10 V; I_D = -2.4 A; T_j = 25 \text{ }^\circ C$	-	5	-	S
$R_G$	gate resistance	$f = 1 \text{ MHz}$	-	14.5	-	$\Omega$
<b>Dynamic characteristics</b>						
$Q_{G(tot)}$	total gate charge	$V_{DS} = -15 V; I_D = -2.4 A; V_{GS} = -10 V; T_j = 25 \text{ }^\circ C$	-	6.2	11	nC
$Q_{GS}$	gate-source charge		-	0.9	-	nC
$Q_{GD}$	gate-drain charge		-	1.1	-	nC
$C_{iss}$	input capacitance	$V_{DS} = -15 V; f = 1 \text{ MHz}; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$	-	309	-	pF
$C_{oss}$	output capacitance		-	41	-	pF
$C_{riss}$	reverse transfer capacitance		-	32	-	pF
$t_{d(on)}$	turn-on delay time		$V_{DS} = -15 V; I_D = -2.4 A; V_{GS} = -10 V; R_{G(ext)} = 6 \Omega; T_j = 25 \text{ }^\circ C$	-	4	-
$t_r$	rise time	-		11	-	ns
$t_{d(off)}$	turn-off delay time	-		16	-	ns
$t_f$	fall time	-		7	-	ns
<b>Source-drain diode</b>						
$V_{SD}$	source-drain voltage	$I_S = -0.9 A; V_{GS} = 0 V; T_j = 25 \text{ }^\circ C$	-	-0.8	-1.2	V



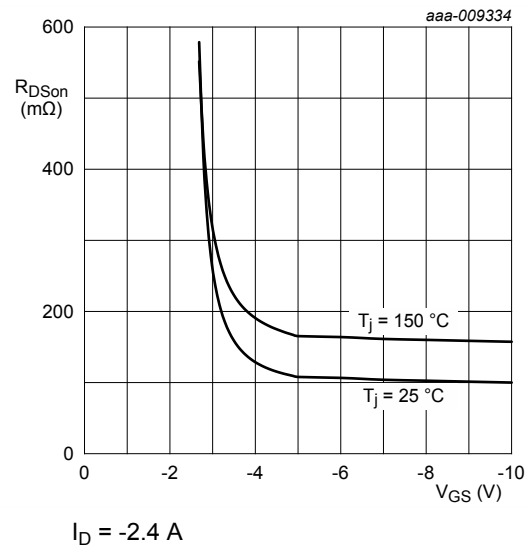
**Fig. 7. Output characteristics: drain current as a function of drain-source voltage; typical values**



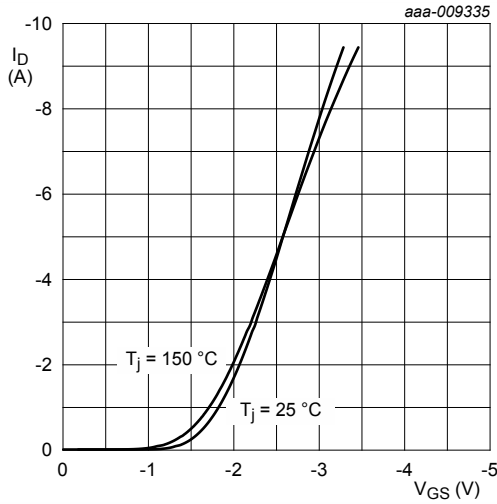
**Fig. 8. Sub-threshold drain current as a function of gate-source voltage**



**Fig. 9. Drain-source on-state resistance as a function of drain current; typical values**

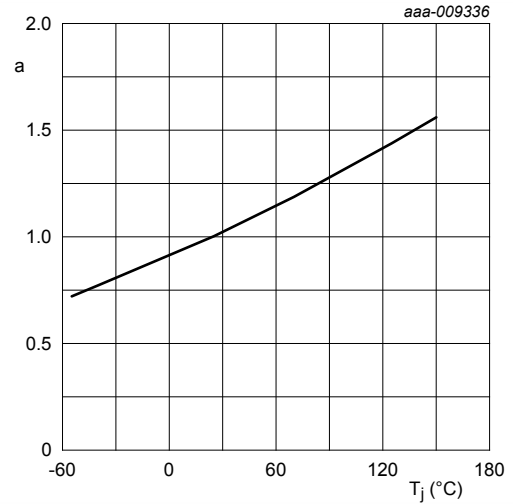


**Fig. 10. Drain-source on-state resistance as a function of gate-source voltage; typical values**



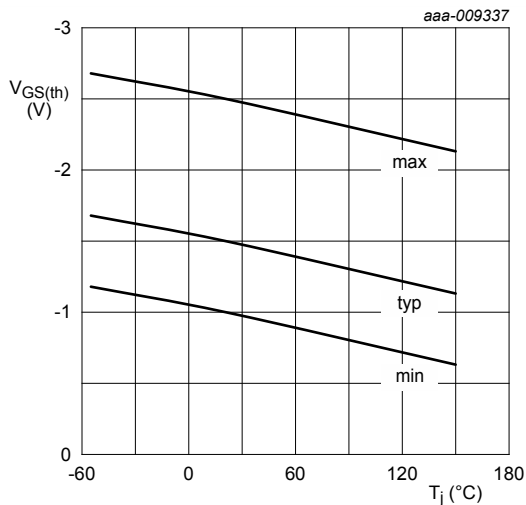
$$V_{DS} > I_D \times R_{DSon}$$

**Fig. 11. Transfer characteristics: drain current as a function of gate-source voltage; typical values**



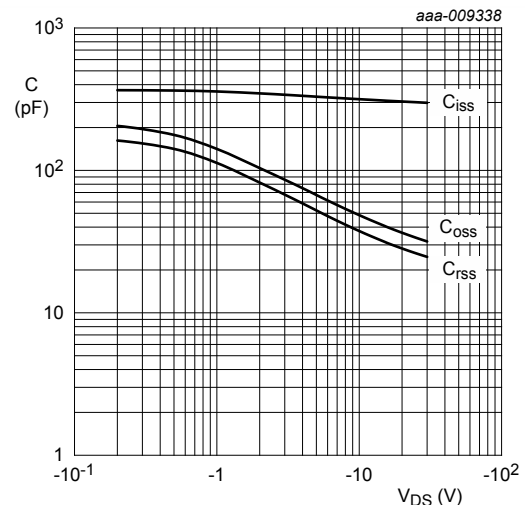
**Fig. 12. Normalized drain-source on-state resistance as a function of junction temperature; typical values**

$$a = \frac{R_{DSon}}{R_{DSon(25^\circ C)}}$$



$$I_D = -0.25 \text{ mA}; V_{DS} = V_{GS}$$

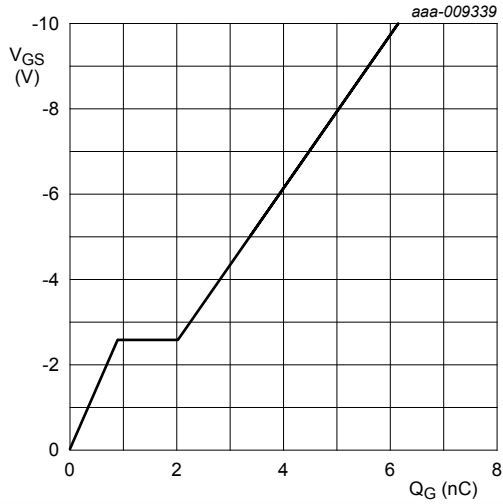
**Fig. 13. Gate-source threshold voltage as a function of junction temperature**



$$f = 1 \text{ MHz}; V_{GS} = 0 \text{ V}$$

**Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values**





$I_D = -2.4 \text{ A}; V_{DS} = -15 \text{ V}; T_{amb} = 25 \text{ }^\circ\text{C}$

Fig. 15. Gate-source voltage as a function of gate charge; typical values

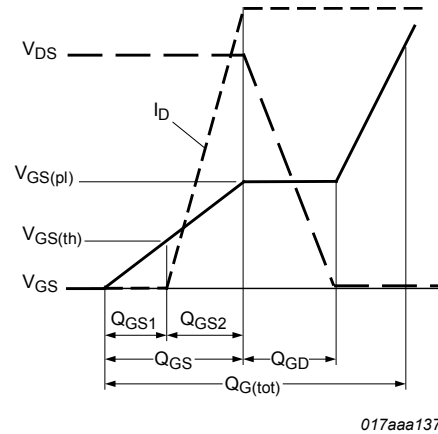
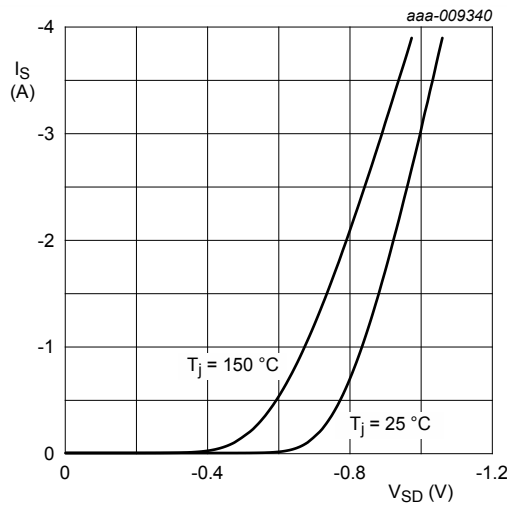


Fig. 16. MOSFET transistor: Gate charge waveform definitions



$V_{GS} = 0 \text{ V}$

Fig. 17. Source current as a function of source-drain voltage; typical values

## 11. Test information

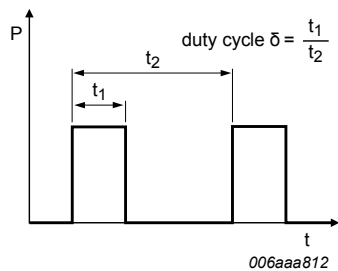
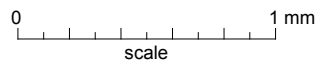
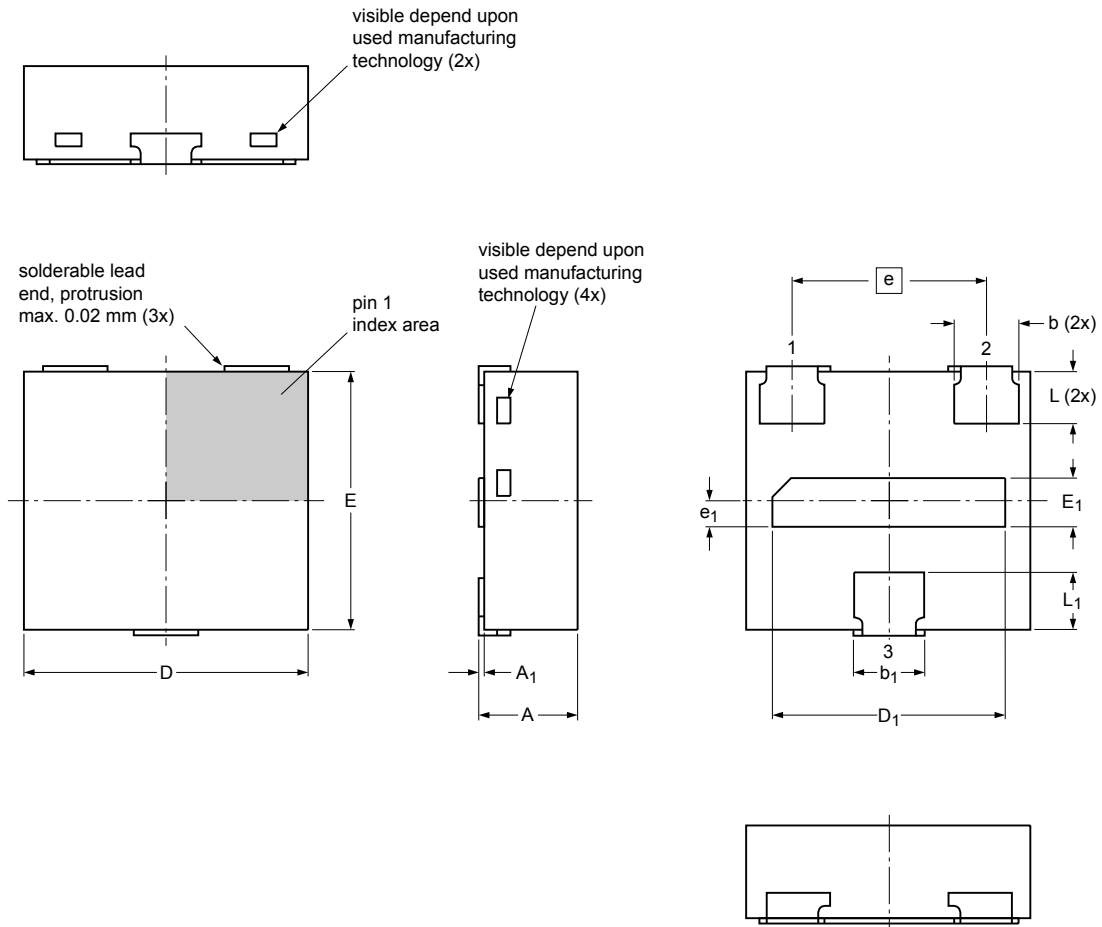


Fig. 18. Duty cycle definition

## 12. Package outline

DFN1010D-3: plastic thermal enhanced ultra thin small outline package; no leads;  
3 terminals; body: 1.1 x 1.0 x 0.37 mm

SOT1215



Dimensions (mm are the original dimensions)

Unit	A	A <sub>1</sub>	b	b <sub>1</sub>	D	D <sub>1</sub>	E	E <sub>1</sub>	e	e <sub>1</sub>	L	L <sub>1</sub>
min	0.34		0.22	0.245	1.05	0.87	0.95	0.16			0.17	0.195
mm nom	0.37		0.25	0.275	1.10	0.90	1.00	0.19	0.75	0.1	0.20	0.225
max	0.40	0.04	0.30	0.325	1.15	0.95	1.05	0.24			0.25	0.275

Note

1. Dimension A is including plating thickness.

sot1215\_po

Outline version	References			European projection	Issue date
	IEC	JEDEC	JEITA		
SOT1215					-13-03-05- 13-03-06

Fig. 19. Package outline DFN1010D-3 (SOT1215)

### 13. Soldering

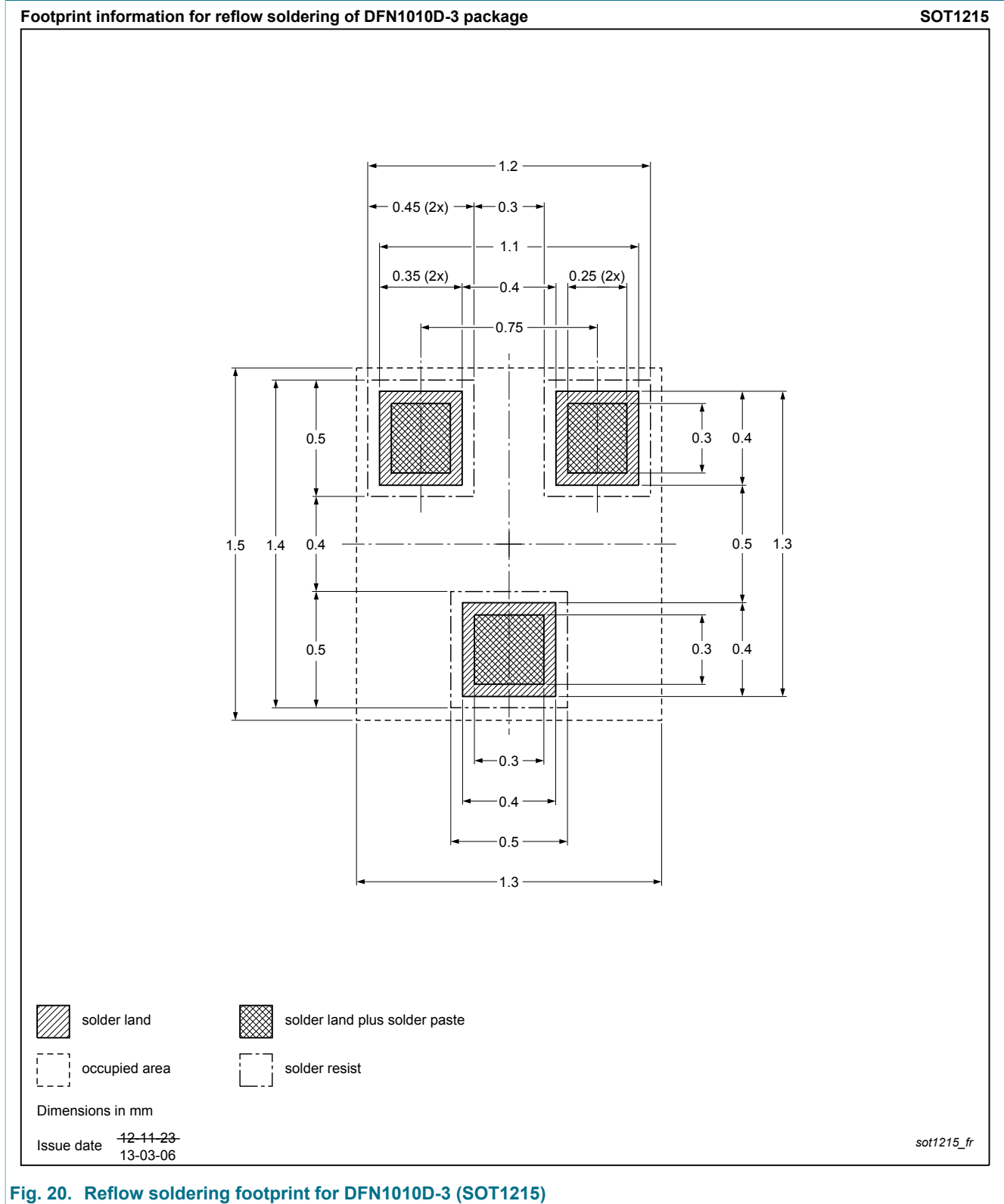


Fig. 20. Reflow soldering footprint for DFN1010D-3 (SOT1215)

## 14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMXB120EPE v.1	20130924	Product data sheet	-	-

## 15. Legal information

### 15.1 Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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[KW40Z](#) [FRDM-MC-LVBLDC](#) [PESD18VF1BSFYL](#) [PMF63UNEX](#) [PSMN4R0-60YS,115](#) [HEF4028BPN](#) [RAPPID-567XFSW](#)  
[MPC565MVR56](#) [MPC574XG-176DS](#) [MPC8548VJAUJD](#) [MPC860PCVR66D4](#) [BCV61A,215](#) [BFU520XAR](#) [BT137-600E](#) [BT137S-600D.115](#)  
[BT138-600E.127](#) [BT139X-600.127](#) [BT258-600R.127](#) [BUK7628-100A118](#) [BUK765R0-100E.118](#) [P5020NSE7VNB](#) [S12ZVML12EVBLIN](#)  
[SCC2692AC1N40](#) [LPC1785FBD208K](#) [LPC2124FBD64/01](#) [LS1020ASN7KQB](#) [LS1020AXN7HNB](#) [LS1020AXN7KQB](#)